# SN74LVC540A-EP OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

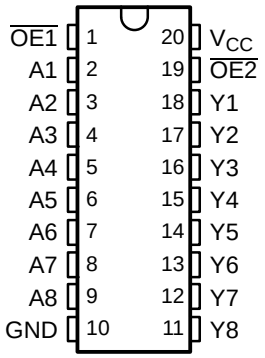
SCAS747A – DECEMBER 2003 – REVISED AUGUST 2005

## FEATURES

- **Controlled Baseline**
  - **One Assembly/Test Site, One Fabrication Site**
- **Extended Temperature Performance of –40°C to 125°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree** (1)
- **Operates From 2 V to 3.6 V**
- **Inputs Accept Voltages to 5.5 V**
- **Max $t_{pd}$ of 5.3 ns at 3.3 V**
- **Typical $V_{OLP}$ (Output Ground Bounce) <0.8 V at $V_{CC}$ = 3.3 V, $T_A$ = 25°C**
- **Typical $V_{OHV}$ (Output $V_{OH}$ Undershoot) >2 V at $V_{CC}$ = 3.3 V, $T_A$ = 25°C**
- **Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V $V_{CC}$)**
- **$I_{off}$ Supports Partial-Power-Down Mode Operation**

(1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

**DW OR PW PACKAGE**
**(TOP VIEW)**




## DESCRIPTION/ORDERING INFORMATION

The SN74LVC540A-EP octal buffer/driver is designed for 2.7-V to 3.6-V $V_{CC}$ operation.

This device is ideal for driving bus lines or buffer-memory address registers. This device features inputs and outputs on opposite sides of the package that facilitate printed circuit board layout.

The 3-state control gate is a 2-input AND gate with active-low inputs so that, if either output-enable ($\overline{OE1}$ or $\overline{OE2}$) input is high, all outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

This device is fully specified for partial-power-down applications using $I_{off}$. The $I_{off}$ circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to $V_{CC}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

**ORDERING INFORMATION**

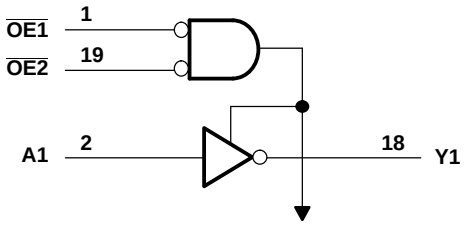
| $T_A$ | PACKAGE(1) | | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|---|---|---|---|---|
| –40°C to 125°C | SOIC – DW | Reel of 2000 | SN74LVC540AQDWREP | C540AEP |
| | TSSOP – PW | Reel of 2000 | SN74LVC540AQPWREP | C540AEP |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

### FUNCTION TABLE

| INPUTS | | | OUTPUT Y |
|---|---|---|---|
| $\overline{OE1}$ | $\overline{OE2}$ | A | |
| L | L | L | H |
| L | L | H | L |
| H | X | X | Z |
| X | H | X | Z |

### LOGIC DIAGRAM (POSITIVE LOGIC)




## Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|---|---|---|---|---|---|
| $V_{CC}$ | Supply voltage range | | –0.5 | 6.5 | V |
| $V_I$ | Input voltage range(2) | | –0.5 | 6.5 | V |
| $V_O$ | Voltage range applied to any output in the high-impedance or power-off state(2) | | –0.5 | 6.5 | V |
| $V_O$ | Voltage range applied to any output in the high or low state(2)(3) | | –0.5 | $V_{CC}$ + 0.5 | V |
| $I_{IK}$ | Input clamp current | $V_I$ < 0 | | –50 | mA |
| $I_{OK}$ | Output clamp current | $V_O$ < 0 | | –50 | mA |
| $I_O$ | Continuous output current | | | ±50 | mA |
| | Continuous current through $V_{CC}$ or GND | | | ±100 | mA |
| $\theta_{JA}$ | Package thermal impedance(4) | DW package | | 58 | °C/W |
| | | PW package | | 83 | |
| $T_{stg}$ | Storage temperature range(5) | | –65 | 150 | °C |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The value of $V_{CC}$ is provided in the recommended operating conditions table.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.
(5) Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.

## Recommended Operating Conditions(1)

| | | | MIN | MAX | UNIT |
|---|---|---|---|---|---|
| $V_{CC}$ | Supply voltage | Operating | 2 | 3.6 | V |
| | | Data retention only | 1.5 | | |
| $V_{IH}$ | High-level input voltage | $V_{CC}$ = 2.7 V to 3.6 V | 2 | | V |
| $V_{IL}$ | Low-level input voltage | $V_{CC}$ = 2.7 V to 3.6 V | | 0.8 | V |
| $V_I$ | Input voltage | | 0 | 5.5 | V |
| $V_O$ | Output voltage | High or low state | 0 | $V_{CC}$ | V |
| | | 3-state | 0 | 5.5 | |
| $I_{OH}$ | High-level output current | $V_{CC}$ = 2.7 V | | –12 | mA |
| | | $V_{CC}$ = 3 V | | –24 | |
| $I_{OL}$ | Low-level output current | $V_{CC}$ = 2.7 V | | 12 | mA |
| | | $V_{CC}$ = 3 V | | 24 | |
| $T_A$ | Operating free-air temperature | | –40 | 125 | °C |

(1) All unused inputs of the device must be held at $V_{CC}$ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | | $V_{CC}$ | MIN | TYP(1) | MAX | UNIT |
|---|---|---|---|---|---|---|---|
| $V_{OH}$ | $I_{OH}$ = –100 µA | | 2.7 V to 3.6 V | $V_{CC}$ – 0.2 | | | V |
| | $I_{OH}$ = –12 mA | | 2.7 V | 2.2 | | | |
| | | | 3 V | 2.4 | | | |
| | $I_{OH}$ = –24 mA | | 3 V | 2.2 | | | |
| $V_{OL}$ | $I_{OL}$ = 100 µA | | 2.7 V to 3.6 V | | | 0.2 | V |
| | $I_{OL}$ = 12 mA | | 2.7 V | | | 0.4 | |
| | $I_{OL}$ = 24 mA | | 3 V | | | 0.55 | |
| $I_I$ | $V_I$ = 0 to 5.5 V | | 3.6 V | | | ±5 | µA |
| $I_{OZ}$ | $V_O$ = 0 to 5.5 V | | 3.6 V | | | ±15 | µA |
| $I_{CC}$ | $V_I$ = $V_{CC}$ or GND | $I_O$ = 0 | 3.6 V | | | 10 | µA |
| | 3.6 V ≤ $V_I$ ≤ 5.5 V(2) | | | | | 10 | |
| $\Delta I_{CC}$ | One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND | | 2.7 V to 3.6 V | | | 500 | µA |
| $C_i$ | $V_I$ = $V_{CC}$ or GND | | 3.3 V | | 4 | | pF |
| $C_o$ | $V_O$ = $V_{CC}$ or GND | | 3.3 V | | 5.5 | | pF |

(1) All typical values are at $V_{CC}$ = 3.3 V, $T_A$ = 25°C.
(2) This applies in the disabled state only.

## Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

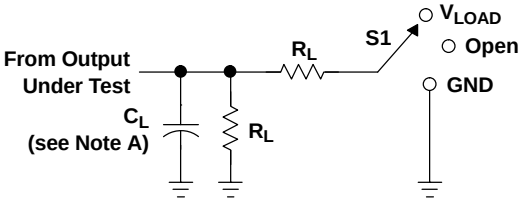
| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC}$ = 2.7 V | | $V_{CC}$ = 3.3 V ± 0.3 V | | UNIT |
|---|---|---|---|---|---|---|---|
| | | | MIN | MAX | MIN | MAX | |
| $t_{pd}$ | A | Y | | 7.1 | 1 | 5.3 | ns |
| $t_{en}$ | $\overline{OE}$ | Y | | 8 | 1 | 6.6 | ns |
| $t_{dis}$ | $\overline{OE}$ | Y | | 8.2 | 1 | 7.4 | ns |

## Operating Characteristics

$T_A$ = 25°C

| PARAMETER | | | TEST CONDITIONS | $V_{CC}$ = 2.5 V | $V_{CC}$ = 3.3 V | UNIT |
|---|---|---|---|---|---|---|
| | | | | TYP | TYP | |
| $C_{pd}$ | Power dissipation capacitance per buffer/driver | Outputs enabled | f = 10 MHz | 56 | 31 | pF |
| | | Outputs disabled | | 3 | 3 | |

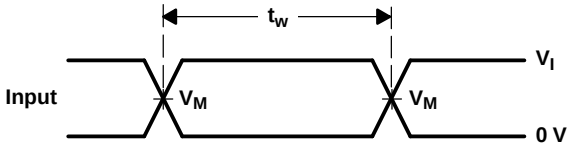
## PARAMETER MEASUREMENT INFORMATION



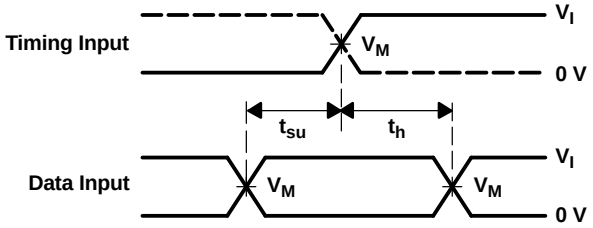

LOAD CIRCUIT

| TEST | S1 |
|---|---|
| $t_{PLH}/t_{PHL}$ | Open |
| $t_{PLZ}/t_{PZL}$ | $V_{LOAD}$ |
| $t_{PHZ}/t_{PZH}$ | GND |

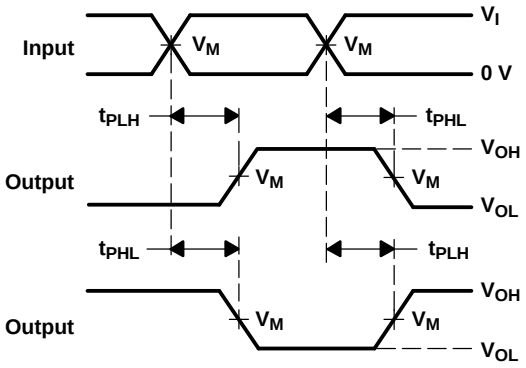
| $V_{CC}$ | INPUTS | | $V_M$ | $V_{LOAD}$ | $C_L$ | $R_L$ | $V_\Delta$ |
|---|---|---|---|---|---|---|---|
| | $V_I$ | $t_r/t_f$ | | | | | |
| 2.7 V | 2.7 V | ≤2.5 ns | 1.5 V | 6 V | 50 pF | 500 Ω | 0.3 V |
| 3.3 V ± 0.3 V | 2.7 V | ≤2.5 ns | 1.5 V | 6 V | 50 pF | 500 Ω | 0.3 V |



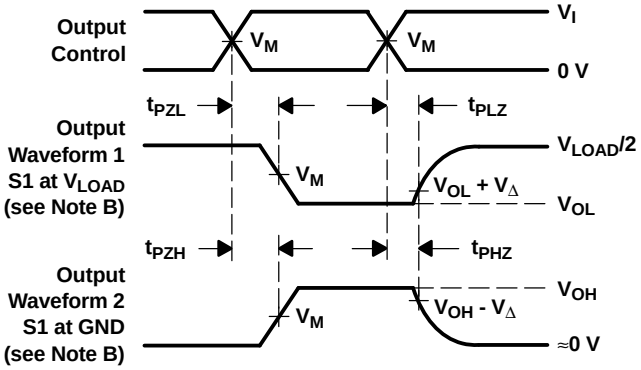

VOLTAGE WAVEFORMS
PULSE DURATION




VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS




VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω.
D. The outputs are measured one at a time, with one transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.
H. All parameters and waveforms are not applicable to all devices.

**Figure 1. Load Circuit and Voltage Waveforms**

## PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| SN74LVC540AQDWREP | Active | Production | SOIC (DW) \| 20 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C540AEP |
| SN74LVC540AQPWREP | Active | Production | TSSOP (PW) \| 20 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C540AEP |
| V62/04665-01XE | Active | Production | SOIC (DW) \| 20 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C540AEP |
| V62/04665-01YE | Active | Production | TSSOP (PW) \| 20 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C540AEP |

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.



**OTHER QUALIFIED VERSIONS OF SN74LVC540A-EP :**

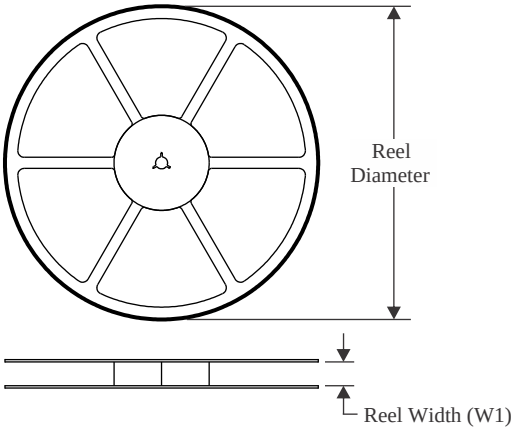
- Catalog : SN74LVC540A
- Automotive : SN74LVC540A-Q1

NOTE: Qualified Version Definitions:

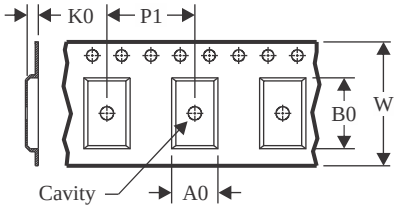
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

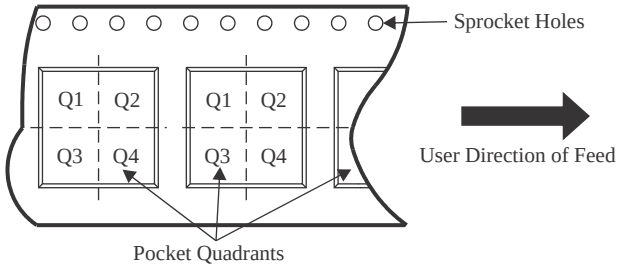



**TAPE DIMENSIONS**




| | |
|---|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

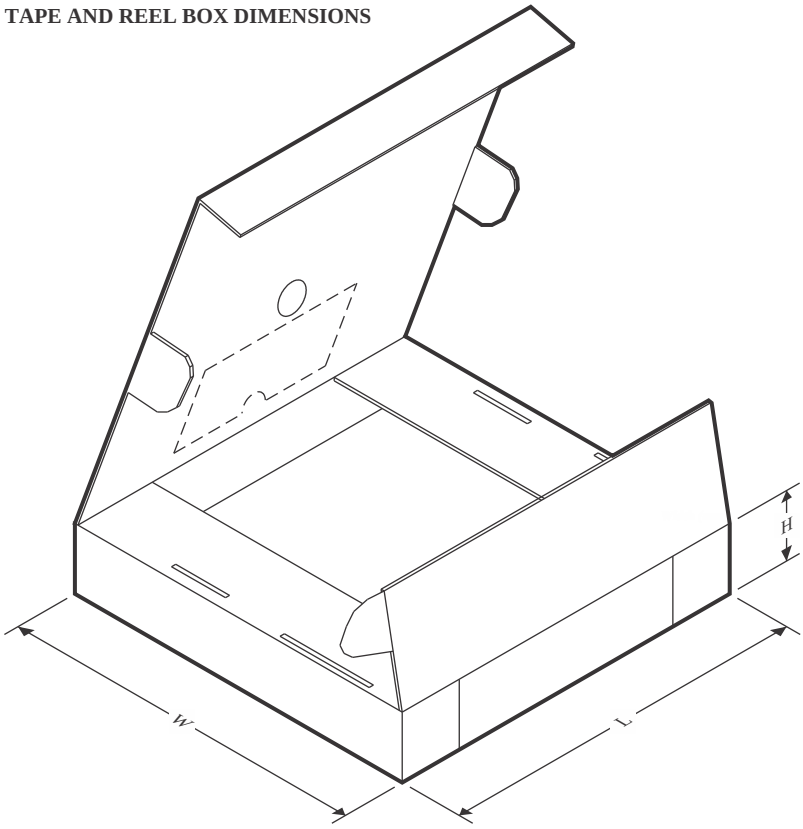
**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**




*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| SN74LVC540AQDWREP | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| SN74LVC540AQPWREP | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS




*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| SN74LVC540AQDWREP | SOIC | DW | 20 | 2000 | 356.0 | 356.0 | 45.0 |
| SN74LVC540AQPWREP | TSSOP | PW | 20 | 2000 | 353.0 | 353.0 | 32.0 |

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Last updated 10/2025